Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

* Except below description page

"Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan

Panasonic

MOS FET FCAB22680L

FCAB22680L Gate resistor installed Dual N-channel MOS FET For lithium-ion secondary battery protection circuits

Features

- Source-source On-state Resistance : RSS(on) typ. = 2.65 m Ω (VGS = 3.8 V)
- CSP (Chip Size Package)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL : Level 1)

Marking Symbol : WF

Packaging

Embossed type (Thermo-compression sealing) : 8 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Boromotor	J	Symbol	Doting	Unit	
Parameter		Symbol	Rating	Unit	
Source-source Voltage		VSS	23	V	
Gate-source Voltage		VGS	±12	V	
Source Current	DC	IS1 *1	13	A	
		IS2 *2	23.4		
		IS3 *3	31.8		
	Pulsed *4	ISp	130		
Total Power Dissipation	DC	PD1 *1	0.59	W	
		PD2 *2	1.9		
		PD3 *3	3.5		
Channel Temperature		Tch	150	°C	
Storage Temperature Range		Tstg	-55 to +150	°C	

■ Thermal Characteristics Ta = 25 °C

Parameter	Symbol	Rating	Unit		
	Rth1 ^{*1}	212			
Thermal Resistance (ch-a)	Rth2 ^{*2}	66	°C / W		
	Rth3 ^{*3}	36			

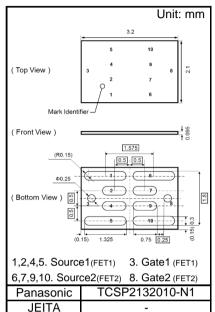
Note *1 Mounted on FR4 board ($25.4 \text{ mm} \times 25.4 \text{ mm} \times t1.0 \text{ mm}$).

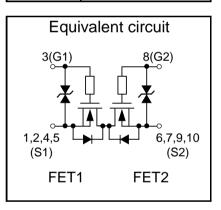
FR4 board partially covered with copper pad ($42~mm^2$ area, 36 μm thickness). *2 Mounted on FR4 board ($25.4~mm\times25.4~mm\times11.0~mm$).

FR4 board fully covered with copper pad (605 mm^2 area, 36 μm thickness).

*3 Mounted on Ceramic board (70 mm \times 70 mm \times t1.0 mm).

*4 t = 10 μ s, Duty Cycle \leq 1 %.





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Code



MOS FET

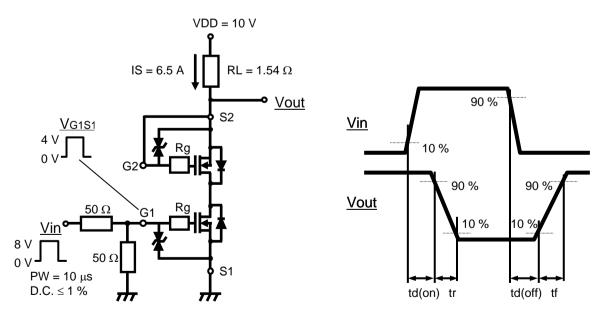
Electrical Characteristics $Ta = 25 \degree C \pm 3 \degree C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	23			V	
Zero Gate Voltage Source Current	ISSS	VSS = 23 V, VGS = 0 V			1.0	μA	
Gate-source Leakage Current	IGSS1	$VGS = \pm 8 V, VSS = 0 V$			±10	μA	
	IGSS2	$VGS = \pm 5 V, VSS = 0 V$			±1.0		
Gate-source Threshold Voltage	Vth	IS = 1.33 mA, VSS = 10 V	0.35	0.9	1.4	V	
Source-source On-state Resistance	RSS(on)1	IS = 6.5 A, VGS = 4.5 V	1.8	2.45	3.2	mΩ	
	RSS(on)2	IS = 6.5 A, VGS = 3.8 V	1.9	2.65	3.45		
	RSS(on)3	IS = 6.5 A, VGS = 3.1 V	2.05	3.0	4.5		
	RSS(on)4	IS = 6.5 A, VGS = 2.5 V	2.3	3.85	7.6		
Body Diode Forward Voltage	VF(s-s)	IF = 6.5 A, VGS = 0 V		0.6	1.0	V	
Input Capacitance ^{*1}	Ciss			4770		pF	
Output Capacitance ^{*1}	Coss	VSS = 10 V, VGS = 0 V, f = 1 kHz		460			
Reverse Transfer Capacitance ^{*1}	Crss			400			
Turn-on Delay Time *1,*2	td(on)	VDD = 10 V, VGS = 0 to 4 V		1.4			
Rise Time ^{*1,*2}	tr	IS = 6.5 A		2.8		μS	
Turn-off Delay Time *1,*2	td(off)	VDD = 10 V, VGS = 4 to 0 V		5.8		μs	
Fall Time ^{*1,*2}	tf	IS = 6.5 A		4.0			
Total Gate Charge ^{*1}	Qg	VDD = 10 V		36			
Gate-source Charge *1	Qgs	VGS = 0 to 4 V		18		nC	
Gate-drain Charge ^{*1}	Qgd	IS = 13 A		12			
Gate Resistance ^{*1}	Rg	f = 10 kHz	400	700	1000	Ω	

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

*1 Guaranteed by design, not subject to production testing.

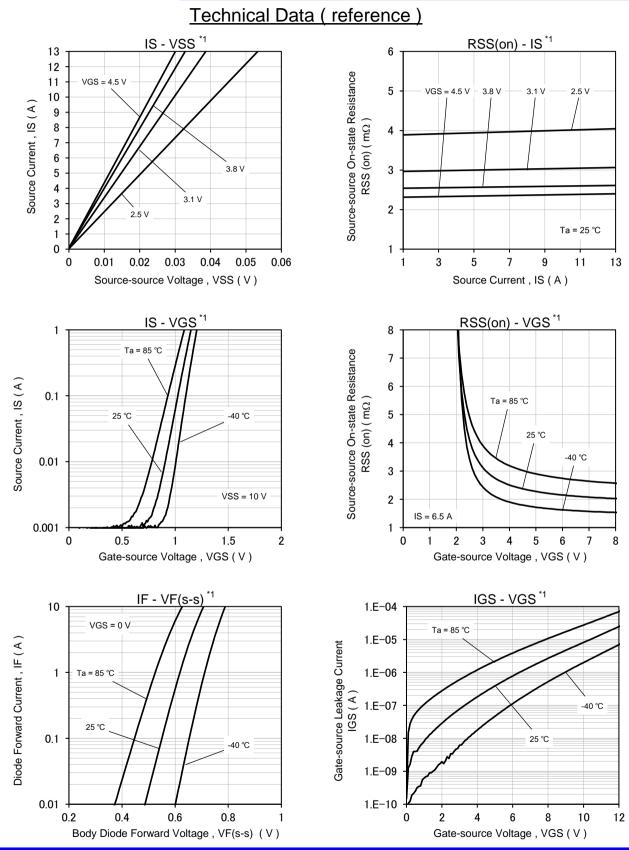
*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.





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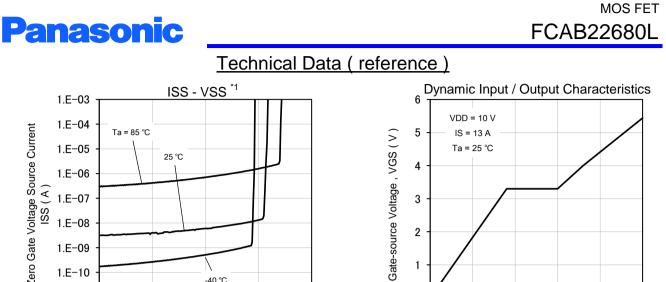


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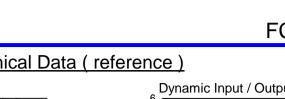
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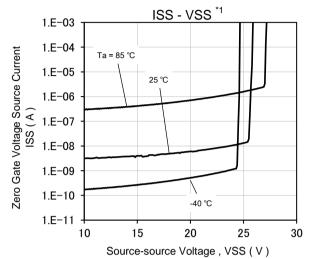
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Total Gate Charge , Qg (nC)

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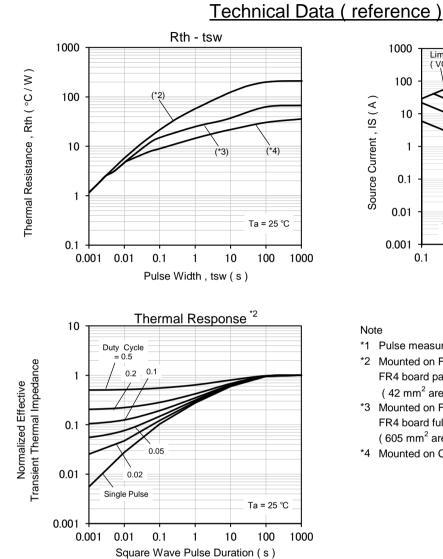
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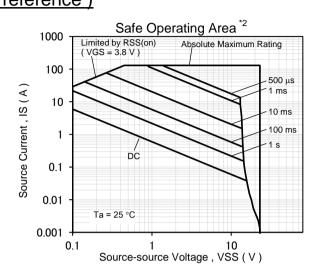




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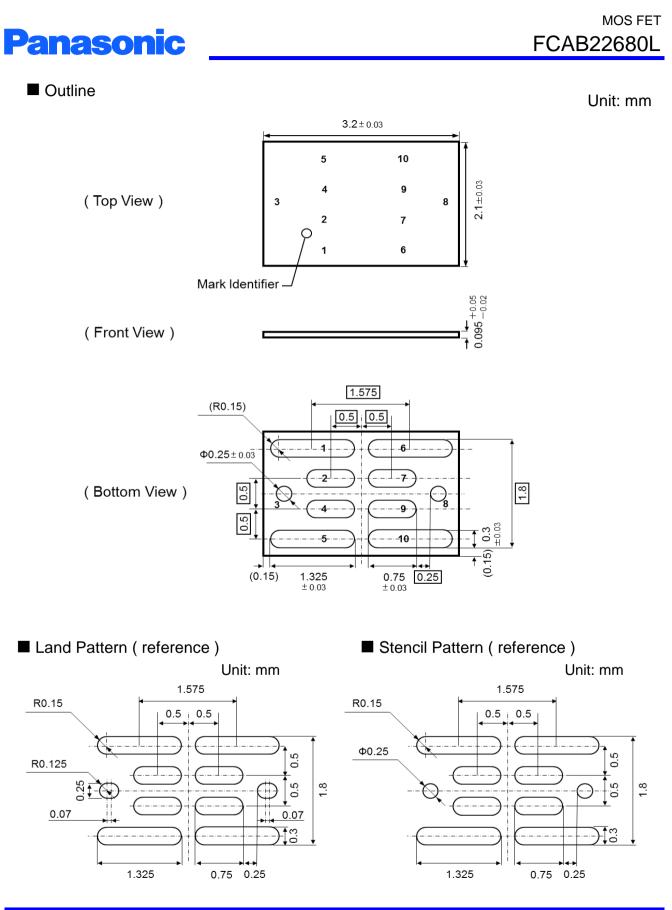
MOS FET FCAB22680L





Note

- *1 Pulse measurement.
- *2 Mounted on FR4 board (25.4 mm \times 25.4 mm \times t1.0 mm). FR4 board partially covered with copper pad (42 mm^2 area, $36 \mu \text{m}$ thickness).
- *3 Mounted on FR4 board (25.4 mm \times 25.4 mm \times t1.0 mm). FR4 board fully covered with copper pad (605 mm² area, 36 µm thickness).
- *4 Mounted on Ceramic board ($70 \text{ mm} \times 70 \text{ mm} \times t1.0 \text{ mm}$).



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